

Article

# Effects of Nitrogen Content on the Structure and Mechanical Properties of $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$ High-Entropy Films by Reactive Sputtering

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**Abstract:** In this study,  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  high-entropy films are prepared by a reactive direct current (DC) magnetron sputtering at different  $\text{N}_2$  flow rates on silicon wafers. It is found that the structure of  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  high-entropy films is amorphous, with  $x = 0$ . It transforms from amorphous to a face-centered-cubic (FCC) structure with the increase of nitrogen content, while the bulk  $\text{Al}_{0.5}\text{CrFeNiTi}_{0.25}$  counterpart prepared by casting features a body-centered-cubic (BCC) phase structure. The phase formation can be explained by the atomic size difference ( $\delta$ ). Lacking nitrogen,  $\delta$  is approximately 6.4% for the five metal elements, which is relatively large and might form a BCC or ordered-BCC structure, while the metallic elements in this alloy system all have a trend to form nitrides like TiN, CrN, AlN, and FeN. Therefore, nitride components are becoming very similar in size and structure and solve each other easily, thus, an FCC (Al-Cr-Fe-Ni-Ti)N solid solution forms. The calculated value of  $\delta$  is approximately 23% for this multicomponent nitride solid solution. The  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  films achieve a pronounced hardness and a Young's modulus of 21.45 GPa and 253.8 GPa, respectively, which is obviously much higher than that of the as-cast  $\text{Al}_{0.5}\text{CrFeNiTi}_{0.25}$  bulk alloys.

**Keywords:** high-entropy films; phase structures; hardness; solid-solution; interstitial phase

## 1. Introduction

High-entropy films (HEFs) are a brand-new type of alloy film, which has been developed recently based on the design concept of high-entropy alloys (HEAs) [1]. HEFs can be defined as multiple-component films with high-entropy mixing. Generally, the HEAs are composed of multi-principal-elements (at least five elements with five at a %  $\leq$  each element content  $\leq$  35 at %) [2,3]. HEAs feature higher mixing entropy than traditional alloys and tend to form disorder face-centered cubic (FCC) and/or body-centered cubic (BCC) phase structures rather than ordered intermetallic compounds [4–6]. Due to severe lattice distortion and solid solution strengthening, attributable to the multi-components, the HEAs show many excellent mechanical properties, such as high-strength, good ductility, and high-wear and corrosion resistances [1]. Based on a similar scientific concept, HEFs have been designed and investigated gradually and show a great potential for application in the coating industry [7–12]. To date, many excellent properties of HEFs have been discovered and studied, such as high-wear resistance [13,14], high-corrosion resistance [15–17], diffusion-barriers effects [18–20], solar-thermal-conversion effects [10,21], plastic-deformation characteristics [22,23],

thermal stabilities [7,24,25], and soft magnetic properties [26]. However, there are few theories that can explain the mechanism of the phase formation of the HEFs.

The phase formation and mechanical properties of  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  high-entropy thin films with different  $\text{N}_2$  flow rates are studied in this paper. The phase structures and mechanical properties of  $\text{Al}_x\text{CrFeNiTi}_{0.25}$  ( $x$ : molar ratio,  $x = 0, 0.25, 0.5, 0.75,$  and  $1.0$ ) bulks have previously been studied systematically [27]. Herein, the optimal composition of  $\text{Al}_x\text{CrFeNiTi}_{0.25}$  ( $x = 0.5$ ) alloy is selected as a magnetron-sputtering target to explore the phase formation mechanism and mechanical properties of high-entropy thin films. Significantly, the phase structures of high-entropy thin films transform from amorphous to FCC with the increase of nitrogen content, while the bulk  $\text{Al}_{0.5}\text{CrFeNiTi}_{0.25}$  alloy attains BCC phase structure. Phase formation mechanism is explored from both theoretical calculations and experiments. Concerning high entropy thin films, the ability for solid solution structure formation is first discussed from the atom radius difference ( $\delta$ ). This study can help to provide new insights into understanding the phase formation mechanism of multi-component alloy thin film solids with small atoms such as nitrogen.

## 2. Materials and Methods

The  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  films were deposited on p-type Si (100) wafers by a direct current (DC) magnetron sputtering using non-equal atomic ratio  $\text{Al}_{0.5}\text{CrFeNiTi}_{0.25}$  targets of  $\Phi$  60 mm in diameter and 2 mm in thickness. The alloy target was prepared by arc-melting and the smelting was repeated at least five times to ensure uniform mixing of components. Prior to deposition, the Si substrates were cleaned sequentially and rinsed by acetone, alcohol, and distilled water in an ultrasonic bath. Pre-sputtering was an effective way to remove oxide or contaminants on the surface of the target. When the base pressure held at  $2.0 \times 10^{-4}$  Pa, high purity argon was injected into the vacuum chamber and the target was cleaned by argon ion bombardment for 15 min at a power of 100 W. The deposition of the  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  films were carried out in an Ar +  $\text{N}_2$  mixed atmosphere under a DC power of 100 W with a working pressure of 0.5 Pa. The schematic diagram of reactive sputtering is shown in Figure 1. The metal atoms escaped the surface of the target due to the bombardment of high energy particles. Due to the nitrogen atmosphere, different metal atoms reacted with N-atoms and were deposited on the substrates in the end. During the deposition, the total flow rate of Ar +  $\text{N}_2$  was maintained at 30 standard cubic centimeters per minute (sccm) and the ratio was  $\text{N}_2/(\text{Ar} + \text{N}_2)$  and  $R_{\text{N}_2}$  was controlled at 0, 10%, 20%, 30%, 40%, and 50%, respectively. The work distance between the substrate and the target was 60 mm and the deposition time was maintained at 60 min. No external heating or bias was used on the substrate during the deposition process.

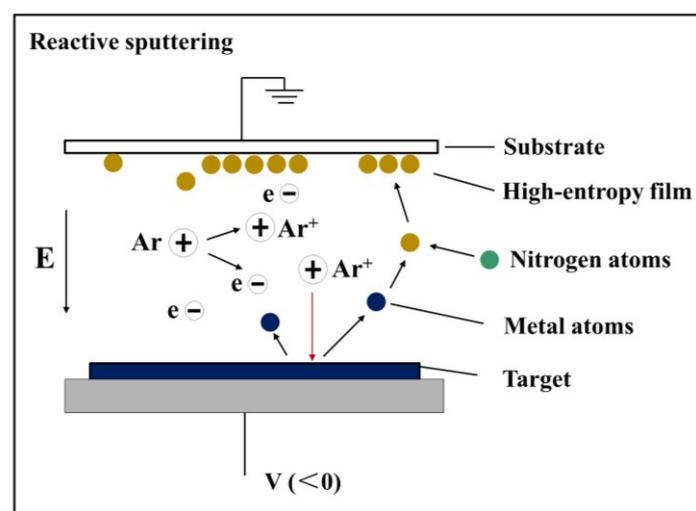


Figure 1. The schematic diagram of reactive sputtering.

The crystal structures of  $(Al_{0.5}CrFeNiTi_{0.25})N_x$  films were analyzed by a glancing-incidence ( $1^\circ$ ) X-ray diffractometer (XRD, BRUKERD8 Discover, Bruker, Karlsruhe, Germany) using the  $Cu K\alpha$  radiation at a scanning rate of  $4^\circ/\text{min}$ . The scanning step was  $0.02^\circ$  with a scanning range of  $20^\circ\text{--}90^\circ$ . The morphology studies and thickness measurements were carried out using field-emission scanning electron microscopy (SEM, Auriga Field Emission Scanning Electron Microscope, Carl Zeiss, Jena, Germany) equipped with an Energy Dispersive X-ray Spectrometer (EDX) operated at 10 kV. The surface roughness of the coatings were measured by an atomic force microscope (AFM, Veeco DI-3100, Bruker, Beijing, China). The hardness and modulus of the as-deposited films were tested at five points for each sample with a nano-indenter using a Berkovich triangular pyramid indenter. The distance between each indentation was  $50\ \mu\text{m}$ . The Poisson's ratio and Elastic modulus of the indenter tip were 0.07 and  $1.141 \times 10^6\ \text{MPa}$ , respectively. Micrographs of indentations were tested by a laser scanning confocal microscope (LSCM, OLS-4100, Olympus, Tokyo, Japan).

### 3. Results and Discussion

#### 3.1. Phase Structures

##### 3.1.1. Phase Formation Mechanism Analysis

The XRD patterns of  $(Al_{0.5}CrFeNiTi_{0.25})N_x$  films deposited at different  $R_{N_2}$  are evaluated in Figure 2. An amorphous structure was observed with  $x = 0$ . As the  $N_2$  flow rate increased, the phase structures of  $(Al_{0.5}CrFeNiTi_{0.25})N_x$  films showed a tendency to crystallize. Using XRD analysis, thin films displayed a simple FCC structure and the grains were nanoscale at about 20 nm. The bulk  $Al_{0.5}CrFeNiTi_{0.25}$  alloys counterpart featured a BCC structure [27]. Due to the high-cooling rate, films were far from the equilibrium that could be achieved by bulk alloys, which led to the difference in structure even if they were the same system. Many similar results have been reported for other system film alloys [16,28–31]. While the metallic elements in this alloy system, which all had trends to form nitrides like TiN, CrN, AlN, and FeN, had results that showed only a simple FCC structure in an XRD pattern, rather than a various nitrides phase. It can be inferred that the solid solution occurred between nitrides in high-entropy thin films. Mutual dissolution between carbides and nitrides has been reported in many studies. Figure 3 shows the UC-ZrC<sub>0.81</sub> pseudo-binary system that showed a miscibility relationship and the substitutional solid solution structure was formed with the carbides as solid solution units [32]. The nitrides also obtained similar results, such as Ti-Al-N, Cr-Al-N, Ti-Cr-N and Ti-Zr-N, Ti-Al-Si-N nitride films [33–37].

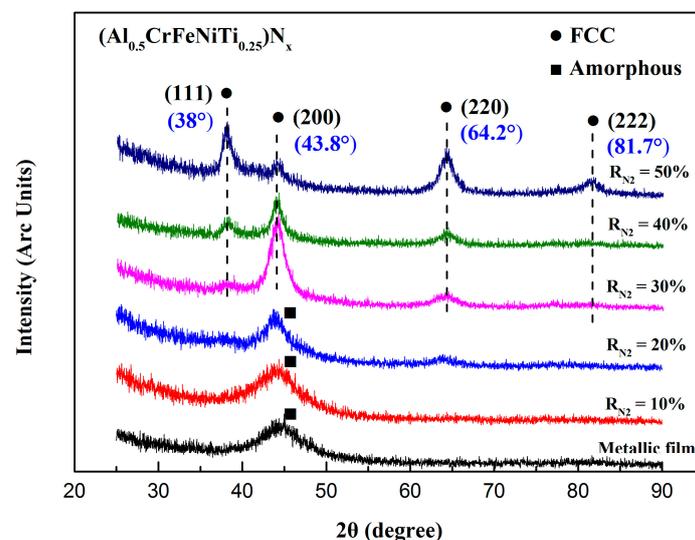
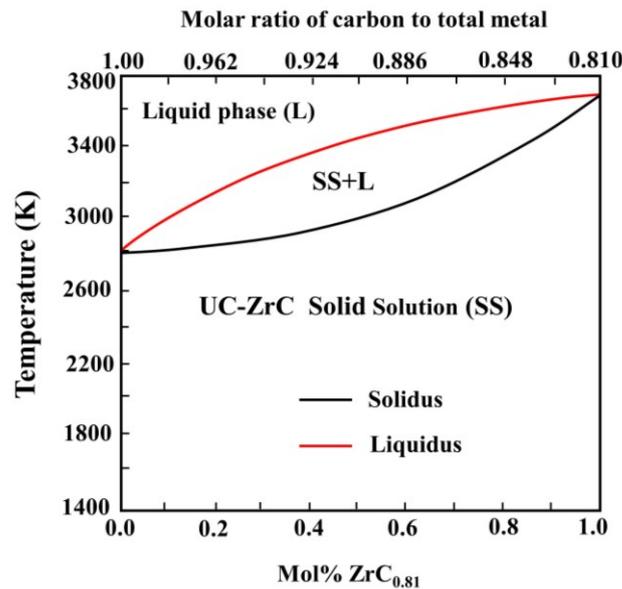
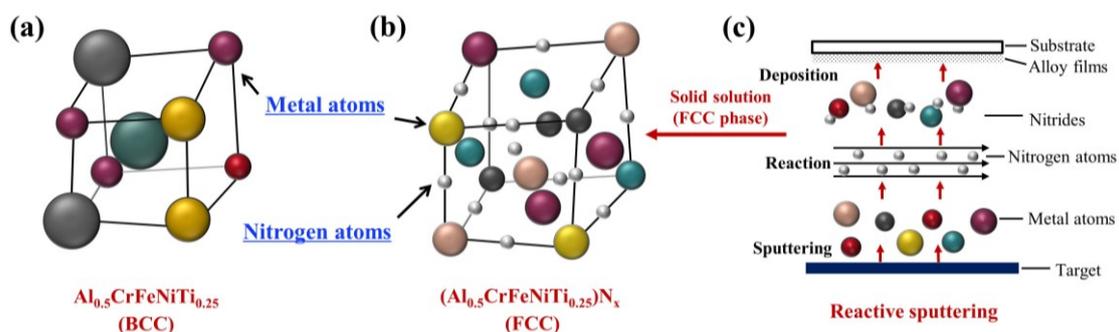


Figure 2. X-ray patterns of the  $(Al_{0.5}CrFeNiTi_{0.25})N_x$  films deposited at different  $R_{N_2}$ .



**Figure 3.** The UC-ZrC<sub>0.81</sub> pseudo-binary phase diagram. Reproduced with the permission from Reference [34].

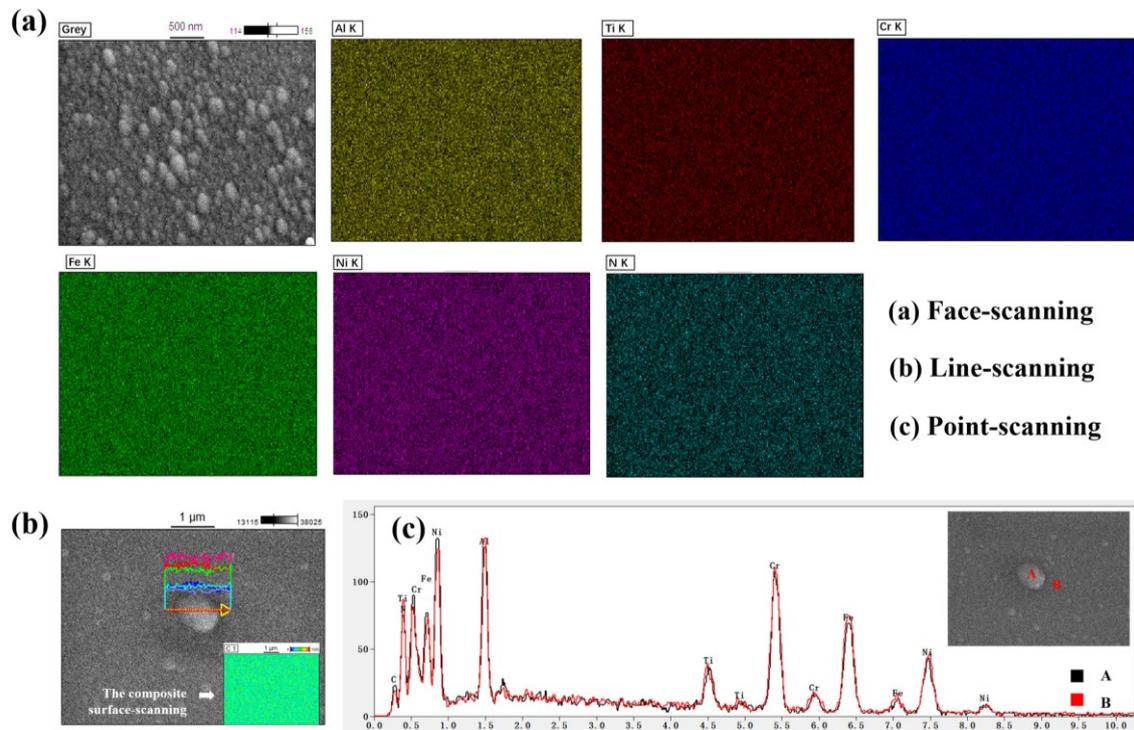
A previous study showed that FCC phases were found to have lower  $\delta$ , whereas BCC phases showed higher  $\delta$  [38]. Regarding (Al<sub>0.5</sub>CrFeNiTi<sub>0.25</sub>)N<sub>x</sub> with  $x = 0$ ,  $\delta$  was approximately 6.4%, which was relatively large, and might form a BCC or ordered BCC structure. Metallic atoms solved each other and formed a BCC solid solution structure (Figure 4a). Accompanying the increase in nitrogen, nitrides formed in (Al<sub>0.5</sub>CrFeNiTi<sub>0.25</sub>)N<sub>x</sub> and were similar in size and structure. The  $\delta$  between nitrides was relatively small, thus an FCC structure might have formed. When R<sub>N2</sub> was equal to 10% and 20%, a low concentration of nitrogen existed in the lattice. However, small amounts of nitrogen cannot facilitate lattice reconstruction. Thus, it still maintained an amorphous structure, however, with a higher nitrogen content, the formation of nitrides was promoted that efficiently improved the order of the lattice. The nitride components were becoming more similar in size and structure and solved each other easily, thus, an FCC (Al-Cr-Fe-Ni-Ti)N<sub>x</sub> solid solution formed, which is shown in Figure 4b,c.



**Figure 4.** Schematic of lattice structure. (a) Al<sub>0.5</sub>CrFeNiTi<sub>0.25</sub> bulk; (b) (Al<sub>0.5</sub>CrFeNiTi<sub>0.25</sub>)N<sub>x</sub> films; and (c) schematic diagram of high-entropy thin film formation.

Figure 5 displays the distribution of component elements of (Al<sub>0.5</sub>CrFeNiTi<sub>0.25</sub>)N<sub>x</sub> thin films deposited at R<sub>N2</sub> = 50% through EDX, including surface, and line and point scanning. As presented in each element map in Figure 5a, the distribution of component elements was uniform, which indicates a segregate-free characteristic. The results of line and point scanning also reflected the same element distribution characteristics. The internal picture in Figure 5b is the composite surface-scanning of this region and segregate-free characteristics can be observed. Viewing the comparative analysis of the

energy spectrum of Point A and Point B in Figure 5c, the distribution of elements was stable and had a slight fluctuation. Moreover, the lattice constant of the FCC solid solution structure was calculated by the Prague formula. The FCC solid solution structure with a lattice constant about 4.093 Å was completely different with nitrides such as TiN, CrN, and so on, which also confirmed the occurrence of a solid solution.



**Figure 5.** Energy dispersive X-ray spectroscopy of  $(Al_{0.5}CrFeNiTi_{0.25})N_x$  high-entropy thin films deposited at  $R_{N_2} = 50\%$ : (a) face-scanning; (b) line-scanning; the insert picture is the composite surface scanning of this region; and (c) point-scanning.

### 3.1.2. Solid Solution Formation Ability

Regarding high-entropy alloys, the solid-solution formation ability was estimated by the value of  $\Omega$  and  $\delta$  [39], which were defined as follows:

$$\Omega = \frac{T_m \Delta S_{mix}}{|\Delta H_{mix}|}$$

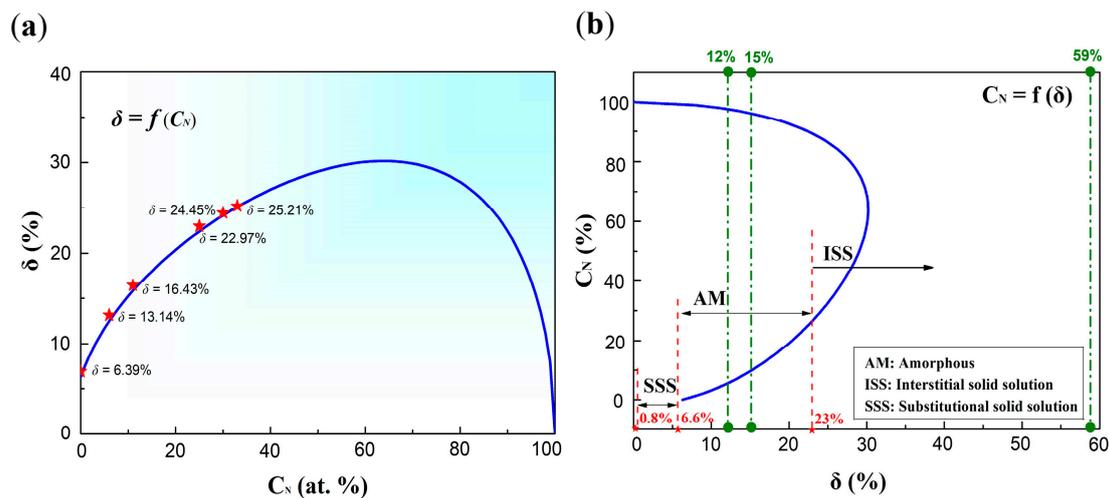
$$\delta = \sqrt{\sum_{i=1}^n c_i (1 - r_i / \bar{r})^2}$$

where  $T_m$  was the melting temperature of the n-elements alloy,  $\Delta S_{mix}$  was the mixing-entropy of an n-element system,  $\Delta H_{mix}$  was the mixing-enthalpy of an n-element system,  $c_i$  was the atomic percentage of the component,  $r_i$  was the atomic radius, and  $\bar{r} = \sum_{i=1}^n c_i r_i$  was the average atomic radius.

Reviewing the previous study, it was concluded that the region where solid-solution structures were formed was in the range of 1.1 to 229.8 for  $\Omega$  and 0.8% to 6.6% for  $\delta$ . The radius of component elements in  $(Al_{0.5}CrFeNiTi_{0.25})N_x$  are shown in Table 1, and the specific  $\Omega$  and  $\delta$  values of  $(Al_{0.5}CrFeNiTi_{0.25})N_x$  at different  $N_2$  flow rates are shown in Table 2.

Concerning  $(Al-Cr-Fe-Ni-Ti)N_x$ , the  $\delta$  was described as a function of nitrogen content, as shown in Figure 6a. The analytical curve was calculated based on the atomic ratio of the target, which was the theoretical value. While different deposition yields of component elements can cause fluctuations in

the atomic ratio, the experimental values were well matched with theoretical values, as shown by the star points in Figure 6a. To clearly distinguish different phase regions of film alloys in this study, the nitrogen content was also described as a function of  $\delta$  in Figure 6b. Regarding  $\text{Al}_{0.5}\text{CrFeNiTi}_{0.25}$ ,  $\delta$  was about 6.4% located in the SSS zone in Figure 6b, and the BCC solid solution phase structure was stable. When increasing the nitrogen content, the FCC structure formed in the  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  system. The calculated value of  $\delta$  was about 23% for that FCC structure. When the nitrogen content was low, the amorphous structure was stable and located in the middle region.



**Figure 6.** (a) Analytical curve of  $\delta$  as a function of nitrogen content in  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  and (b) analytical curve of nitrogen content as a function of  $\delta$  in  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  films (12% according to Inoue Principle, 15% and 59% according to the Hume–Rothery Rule).

**Table 1.** The radius of component elements in  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  films.

Element	N	Al	Ti	Cr	Fe	Ni
Radius (nm)	0.071	0.1434	0.1445	0.1249	0.1241	0.1246

**Table 2.** The nitrogen content,  $\Omega$  value,  $\delta$  value, and the roughness of films at different  $R_{\text{N}_2}$ .

$R_{\text{N}_2}$ (%)	0	10	20	30	40	50
Nitrogen Content (at %)	0	5.94	10.97	25.10	29.55	32.21
$\Omega$	1.60	1.31	0.44	0.23	0.20	0.19
$\delta$	6.39%	13.14%	16.43%	22.97%	24.45%	25.21%
$R_a$ (nm)	1.375	1.574	3.780	4.542	4.490	5.574

### 3.2. Deposition Rates

Figure 7 presents the deposition rate of  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  as a function of  $R_{\text{N}_2}$  and the exact value of thickness is shown in the internal table. Following the addition of nitrogen, the deposition rate of films was significantly reduced by about 30%. During the deposition, the total flow rate of Ar +  $\text{N}_2$  was maintained at 30 sccm. Thus, the density of argon decreased gradually with the increase of  $\text{N}_2$  flow rate and resulted in a lower efficiency of argon-ion bombardment of the target. Under higher  $R_{\text{N}_2}$ , the deposition rate continued to slow and maintain a lower sputtering yield. Added to the effect caused by low argon gas density, the ceramicization of the target surface was also an important factor. This was mainly due to the N-containing layer that formed on the target surface, which reduced the conductivity of the target and resulted in a low sputtering yield. This phenomena was “target poisoning” [40,41].

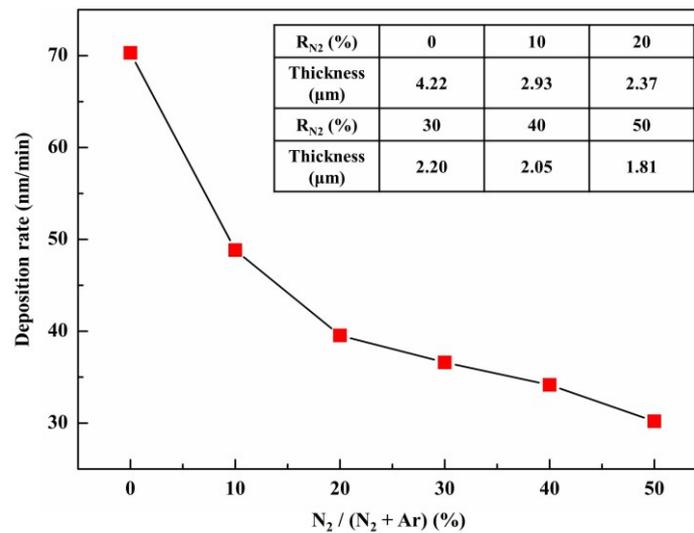


Figure 7. Deposition rates of  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  films at different  $R_{N_2}$ .

### 3.3. Surface Morphologies

The AFM images and SEM micrographs of the  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  films at different  $R_{N_2}$  are shown in Figure 9. Initially, a very dense and smooth surface with low surface roughness was obtained. Looking at SEM micrographs, it was observed that a small amount of nanostructure precipitation occurred as the  $R_{N_2}$  increased to 10%. When the  $\text{N}_2$  flow rate increased, the number and particle size of the nanostructures were increased significantly. Viewing the AFM images, many needle nanostructures were also observed in the high-entropy thin films. Additionally, the roughness of films was measured by AFM. The value of  $R_a$  gradually became larger and the exact value of surface roughness at different  $R_{N_2}$  is shown in Table 2. The heights of the needle structure in all the HEFs were less than 60 nm, which was consistent with the results since the as-deposited HEFs were smooth and homogeneous, as shown in SEM micrographs.

The surface nanostructures displayed by AFM images were different from each other and the size of the needle structures became larger with the increase of  $R_{N_2}$ . These nano-scaled needle structures were related to the structure zone models, which had a great impact on the microstructural evolution of thin film. Initially, as  $R_{N_2}$  was low, the growth of the HEFs effect by nitrogen ions was limited. The nucleation barrier was generally expected to be small, which contributed to the formation of randomly oriented islands for films deposited on the silicon substrates without substrate heating. Accompanying the increase of  $R_{N_2}$ , a strong driving force was obtained, which facilitated the surface atom diffusion and grain boundary motion. To achieve a stable state, the overall surface and interface energy were minimized through forming the new islands. Islands with lower energy consumed the others. Thus, the roughness of the HEFs increased gradually with the increase of  $R_{N_2}$ .

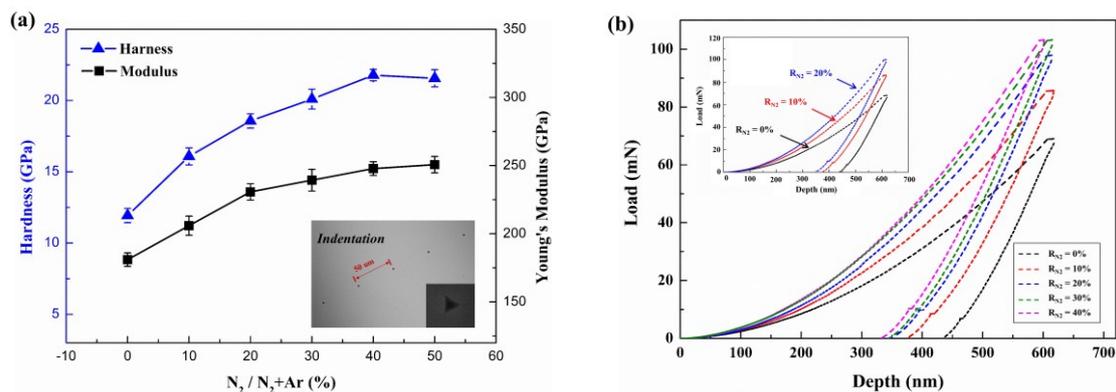
### 3.4. Mechanical Properties

Figure 8a displays the hardness and Young's modulus of  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  films as a function of the  $\text{N}_2$  flow rate. Through the increase of the nitrogen content, the hardness and Young's modulus of the films showed a significant upward trend. The high-entropy thin films showed the highest hardness and Young's modulus at 21.78 GPa and 253.8 GPa, respectively. Compared with the bulk  $\text{Al}_{0.5}\text{CrFeNiTi}_{0.25}$  alloys (the value of hardness was about 6 GPa), the hardness of the  $(\text{Al}_{0.5}\text{CrFeNiTi}_{0.25})\text{N}_x$  HEFs was improved significantly. Considering the load-depth curves of Figure 8b, the manifest and precise change of the hardness and Young's modulus of the HEFs was obtained. When the probe depressed into the same depth, a larger force was required with the increase of the  $R_{N_2}$ . This was attributed to the fact that solid solution significantly increased the hardness. It is

well known that solid solution strengthening increases the yield strength of the material by increasing the stress  $\tau$  to move dislocations [42]:

$$\Delta\tau = Gb\epsilon^{3/2}\sqrt{c}$$

where  $c$  was the concentration of the solute atoms,  $G$  was the shear modulus,  $b$  was the magnitude of the Burger's vector, and  $\epsilon$  is the lattice strain due to the solute. While increasing the  $N_2$  flow rates, the parameters  $c$  and  $\epsilon$  were increased correspondingly, which resulted in a higher  $\tau$  value. Thus, the effect of solid-solution strengthening was enhanced gradually with the increase of  $R_{N_2}$ . When the  $R_{N_2} = 40\%$  and  $50\%$ , the nitrogen content in films increased slowly. The difference in nitrogen content was only 2.66%, as shown in Table 2. The mechanical properties of the HEFs became stable.



**Figure 8.** Mechanical properties of  $(Al_{0.5}CrFeNiTi_{0.25})N_x$  films deposited at different  $R_{N_2}$ . (a) Hardness and modulus and (b) load-depth curve.

#### 4. Discussion

It is well known that the solid solutions can be divided into three types: Substitutional solid solutions; interstitial solid solutions; and vacancy solid solutions. Hume–Rothery rules are a set of basic rules that describe the formation of substitutional and interstitial solid solutions. Regarding a substitutional solid solution, the atomic radius of the solute and solvent atoms must differ by no more than 15%, while solute atoms should have a radius no larger than 59% of the radius of the solvent atoms for an interstitial solid solution [43]. However, the non-metallic elements, such as H, B, C, and N, having a very small atomic radius can form compounds with metal elements. When the ratio of a non-metal atom radius to a metal atom radius ( $R_x/R_M$ ) is less than 0.59, the compounds have a simple structure such as  $M_4X$ ,  $M_2X$ ,  $MX$ ,  $MX_2$ , which is called an interstitial phase. When  $R_x/R_M > 0.59$ , the compounds have a complex structure such as  $Fe_3C$ , thus, there is an interstitial compound [44]. Regarding  $(Al_{0.5}CrFeNiTi_{0.25})N_x$ , the metallic elements all satisfy the formation rule for an interstitial phase and different nitrides with simple structures can be formed. The metallic elements will tend to be ionic and the ionic radius might well reflect the actual particle. Since most of the elements in this alloy system are transitional metals, their ionic radii are very close to each other. Nitride components are becoming more similar in size and structure and solve each other easily. Thus, the FCC structured phase is formed in  $(Al_{0.5}CrFeNiTi_{0.25})N_x$ .

The correlation between the composition, processing, microstructures, and the properties of high-entropy thin films can be summarized systematically and is shown in Figure 10. First, the films are prepared by a magnetron sputtering technique and different  $N_2$  flow rates are selected to adjust the composition as well as to change the microstructures. This finds that the nitrogen content in the thin films increases gradually with the increase of the nitrogen content and the structure of films transform from amorphous to FCC. Second, it is further found that the mechanical properties (hardness/Young's modulus) of the high-entropy crystalline films are much better than the high-entropy amorphous films. All told, there is an increasing trend of hardness with higher nitrogen for the high-entropy thin

films. Third, due to the difference in the preparation process, the phase structure and the properties of the films are different from the bulk samples, although they are in the same composition system. This study can help enrich the cognition between composition processing, microstructures, and the properties for high-entropy materials, especially for high-entropy thin films.

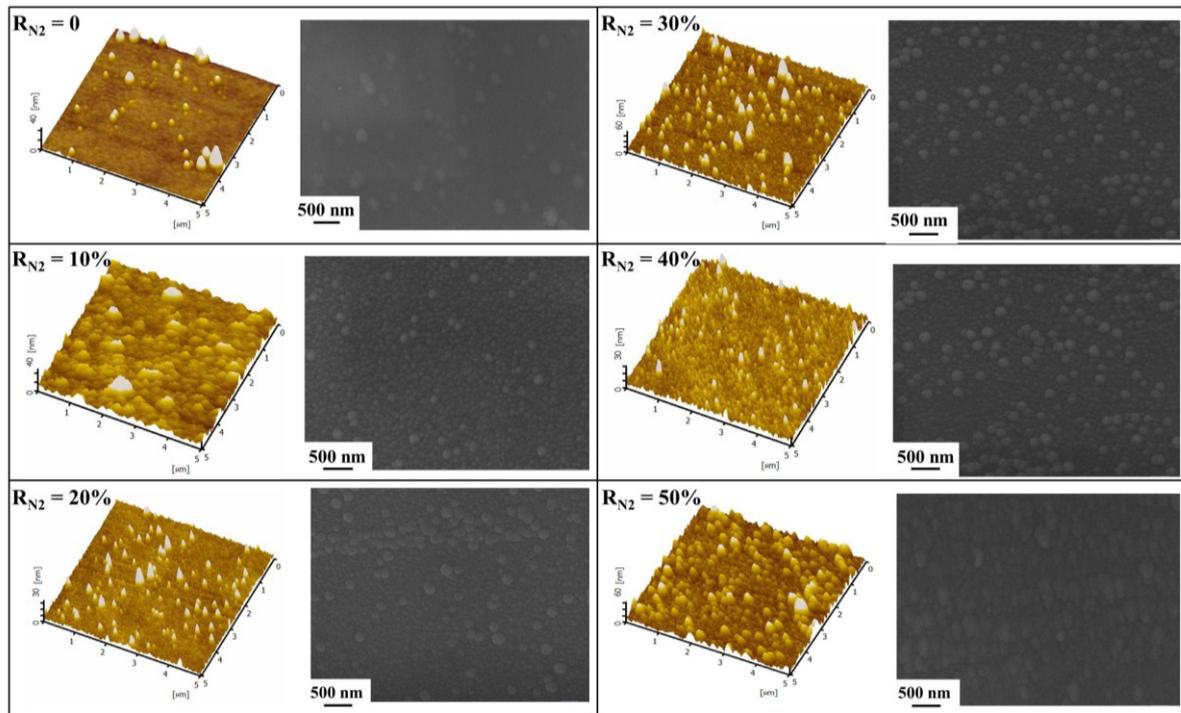


Figure 9. AFM images and SEM micrographs of  $(Al_{0.5}CrFeNiTi_{0.25})N_x$  films at different  $R_{N_2}$ .

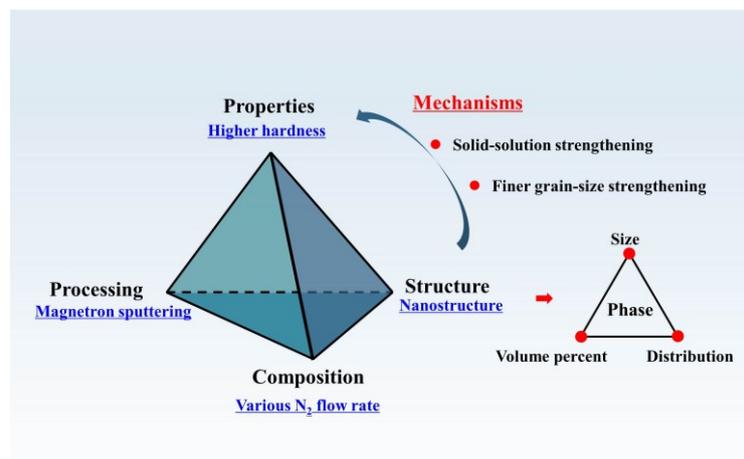


Figure 10. Relationship between composition, processing, properties, and the structures of high-entropy films.

## 5. Conclusions

The  $(Al_{0.5}CrFeNiTi_{0.25})N_x$  high-entropy thin films were deposited on silicon wafers through magnetron sputtering without substrate bias and heating. It was found that the phase structures of the HEFs transformed from an amorphous to an FCC structure with the increase in nitrogen content—the formation of a nitride solid solution was the main reason. Using the XRD analysis, the grain size was nanoscale at about 20 nm. The formation ability of the solid solution phase for the Al-Cr-Fe-Ni-Ti-N

system film alloys was discussed regarding  $\delta$ . When the value of  $\delta$  was higher than 23%, the solid solution structures were stable in  $(Al_{0.5}CrFeNiTi_{0.25})N_x$  thin films. The  $(Al_{0.5}CrFeNiTi_{0.25})N_x$  HEFs deposited at  $R_{N2} = 40\%$  and  $50\%$  yielded a maximum hardness and modulus of 21.78 GPa and 253.8 GPa, respectively, which is much higher than the as-cast  $Al_{0.5}CrFeNiTi_{0.25}$  bulk alloys. The enhancement in hardness was mainly attributed to solid-solution strengthening and the lattice distortion. Additionally, smaller grain-size was a beneficial factor for increasing hardness.

**Author Contributions:** X.-H.Y. finished the preparation of high-entropy thin films. X.-H.Y. and W.-B.L. together carried out analyzing and writing. K.Z. provided equipment. Y.Z. offered the theoretical guidance.

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**Conflicts of Interest:** The authors declare no conflict of interest.

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